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## N<sub>2</sub> positively charged defects in diamond. A Quantum Mechanical investigation of the structural, electronic, EPR and vibrational properties.

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## Formation Energy versus supercell size

In Table S1 the defect formation energy,  $E_f$ , is reported as a function of the supercell size.  $E_f$  is defined as the difference between  $E_{def}$ , the total energy of the defective system, and M times  $E_{diam}$ , the total energy of pristine diamond per atom (-38.05591  $E_h$ ), plus  $E_{N_2}$ , the total energy of the isolated N<sub>2</sub> molecule (-109.31265  $E_h$ ). On going from S<sub>64</sub> to S<sub>1000</sub>  $E_f$  changes by only 0.004  $E_h$ , that is about 0.11 eV.

Table S1: Defect formation energy of the  $N_2^+$  system as a function of the supercell size. M is the number of carbon atoms contained in the defective system,  $E_{def}$  is the total energy of the defective system, while  $E_f$  is the formation energy.

Supercell	М	E <sub>def</sub>	$E_f$	
		$(E_h)$	$(\mathbf{E}_h)$	
S <sub>64</sub>	62	-2469.21468	-0.436	
S <sub>216</sub>	214	-8253.70620	-0.429	
S <sub>512</sub>	510	-19518.25479	-0.429	
S <sub>1000</sub>	998	-38089.54174	-0.432	

## Hyperfine coupling and quadrupolar $(P_{\parallel})$ constants

Table S2 reports the data in Gauss, as required by one of the referees, whereas in the corresponding table of the main text they are in MHz, as in the most recent experimental paper (Ref.[1]).

Site	A <sub>iso</sub>	$B_1$	$B_2$	<b>B</b> <sub>3</sub>	P	
	+39.35	+17.66	-8.83	-8.83	-0.87	
$^{14}N$	+37.86	+17.55	-8.77	-8.77	-0.80	Ref.[1]
	+37.67	+17.53	-8.77	-8.77	-	Ref.[2]
<sup>15</sup> N	-55.20	-24.77	+12.39	+12.39	-	
$^{13}C_{1}$ (a)	-4.37	+0.91	-0.62	-0.29	-	
$^{13}C_{1}$ (a)	-4.39	-	-	-	-	Ref.[1]
$^{13}C_2$ (b)	+3.97	+1.48	-0.80	-0.68	-	
$^{13}C_3$ (c)	+1.32	+0.60	-0.31	-0.29	-	
${}^{13}C_4$ (d)	+1.26	+0.47	-0.25	-0.22	-	
${}^{13}C_5$ (h)	+0.31	+0.16	-0.10	-0.06	-	
${}^{13}C_6$ (e)	-0.15	+0.33	-0.19	-0.15	-	
$^{13}C_{7} \ (f)$	+0.13	+0.34	-0.20	-0.14	-	

Table S2: Hyperfine coupling and quadrupolar (P<sub>||</sub>) constants (Gauss) for the doublet state ( $S_z = 1/2$ ) of the N<sub>2</sub><sup>+</sup> defect based on the 6-31G-J<sup>\*</sup> basis set.  $\mathscr{B}$  tensor components are sorted so that  $|B_1| > |B_2| > |B_3|$ . The constants are in descending  $|A_{iso}|$  order for the carbon atoms (from C<sub>1</sub> to C<sub>7</sub>). The labels in round brackets are those shown in Fig. 1 of the main text.



Figure S1: Sketch of the band structures of the  $N_2$ ,  $N_2^+$  and  $N_2^{++}$  defects in diamond. The  $N_2$  and  $N_2^{++}$  ground state is a closed shell singlet; it is a doublet for  $N_2^+$ . Filled and empty circles (black for  $N_2$  and  $N_2^{++}$ , red for  $N_2^+$ ) indicate occupied and virtual defect levels. In the  $N_2^+$  case the smallest gap corresponds to a transition between beta spin levels, highlighted by a red arrow. Data refer to the  $S_{64}$  supercells.

- [1] O. Tucker, M. Newton and J. Baker, Phys. Rev. B, 1994, 50, 15586–15596.
- [2] J. Van Wyk and J. Loubser, J. Phys. C: Solid State Phys., 1983, 16, 1501.